

### 描述 / Descriptions

SOT-23 塑封封装 N 沟道 MOS 场效应管。N-CHANNEL MOSFET in a SOT-23 Plastic Package.

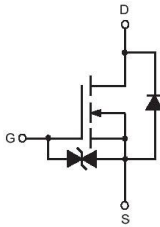
### 特征 / Features

灵敏的控制级触发电流和很低的维持电流。静电保护达 2KV。无卤产品。  
Sensitive gate trigger current and Low Holding current.ESD protected up to 2KV. HF product.

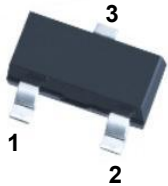
### 用途 / Applications

用作一般的开关和相位控制。  
Intended for use in general purpose switching and phase control applications.

### 内部等效电路 / Equivalent Circuit



### 引脚排列 / Pinning



PIN 1 : G      PIN 2 : S      PIN 3 : D

### 印章代码 / Marking

Marking	H702K
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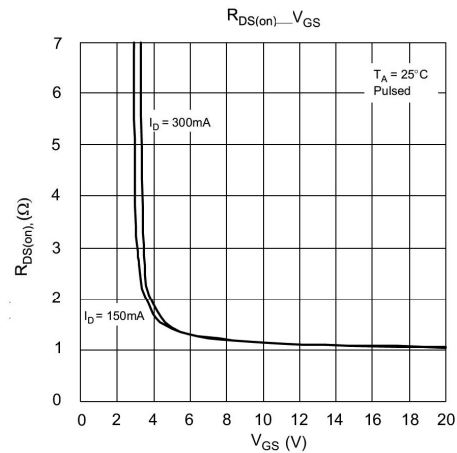
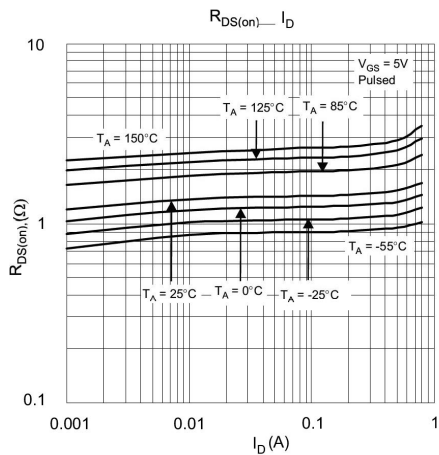
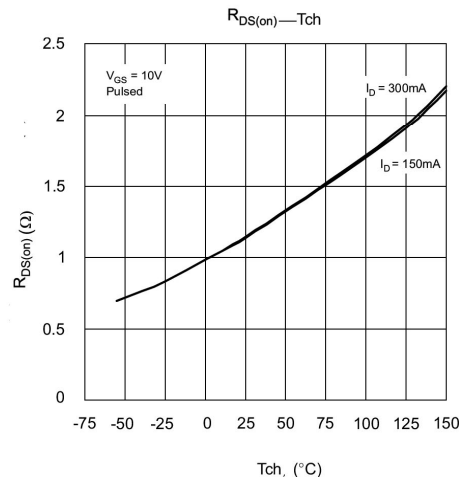
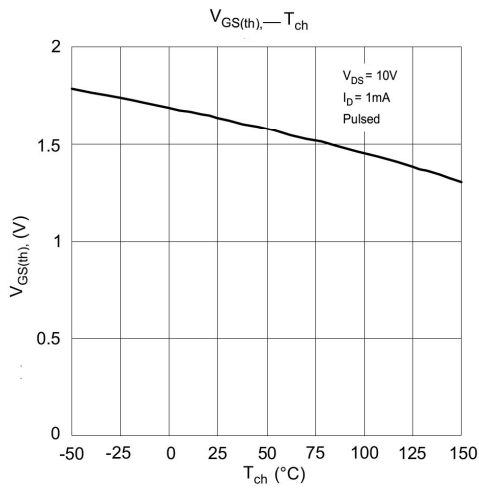
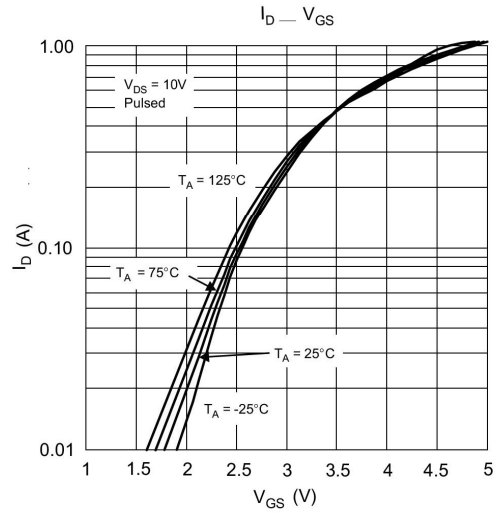
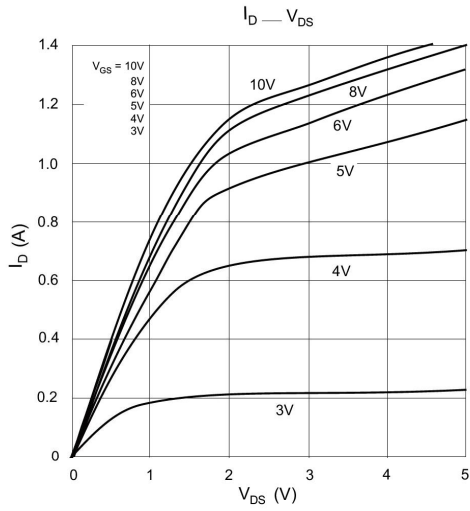
**极限参数 / Absolute Maximum Ratings(Ta=25°C)**

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	$V_{DSS}$	60	V
Drain-Gate Voltage	$V_{DGR}$	60	V
Drain Current - Continuous	$I_D$	300	mA
Drain Current - Pulsed	$I_{DM}$	800	mA
Gate-Source Voltage - Continuous	$V_{GSS}$	±20	V
Power Dissipation	$P_D$	350	mW
Storage Temperature Range	$T_{stg}$	-55~150	°C

**电性能参数 / Electrical Characteristics(Ta=25°C)**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit		
Drain-Source Breakdown Voltage	$V_{DSS}$	$V_{GS}=0$ $I_D=10\mu A$	60			V		
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{GS}=0$ $V_{DS}=60V$			1.0	$\mu A$		
Gate-Source Leakage current	$I_{GSS}$	$V_{DS}=0V$ $V_{GS}=\pm 20V$			±10	$\mu A$		
Static Drain-Source On-Resistance	$R_{DS(on)(1)}$	$V_{GS}=10V$ $I_D=0.5A$			5	$\Omega$		
	$R_{DS(on)(2)}$	$V_{GS}=5V$ $I_D=0.05A$			5.5	$\Omega$		
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V$ $I_S=250mA$			1.5	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	1.0	1.6	2.5	V		
Forward Transconductance	$Y_{fs}$	$V_{DS}=10V$ $I_D=0.2A$	80			ms		
Drain-Source On-Voltage	$V_{DS(on)(1)}$	$V_{GS}=10V$ $I_D=500mA$			2.5	V		
	$V_{DS(on)(2)}$	$V_{GS}=5.0V$ $I_D=50mA$			0.275	V		
Turn-On Time	$t_{d(on)}$	$V_{DD}=25V$ $R_G=25\Omega$ $V_{gen}=10V$			20	ns		
Turn-Off Time	$t_{d(off)}$						40	ns
Input Capacitance	$C_{iss}$	$V_{ds}=25V$ $f=1MHz$	$V_{GS}=0V$		50	pF		
Output Capacitance	$C_{oss}$						25	pF
Reverse Transfer Capacitance	$C_{rss}$						5	pF

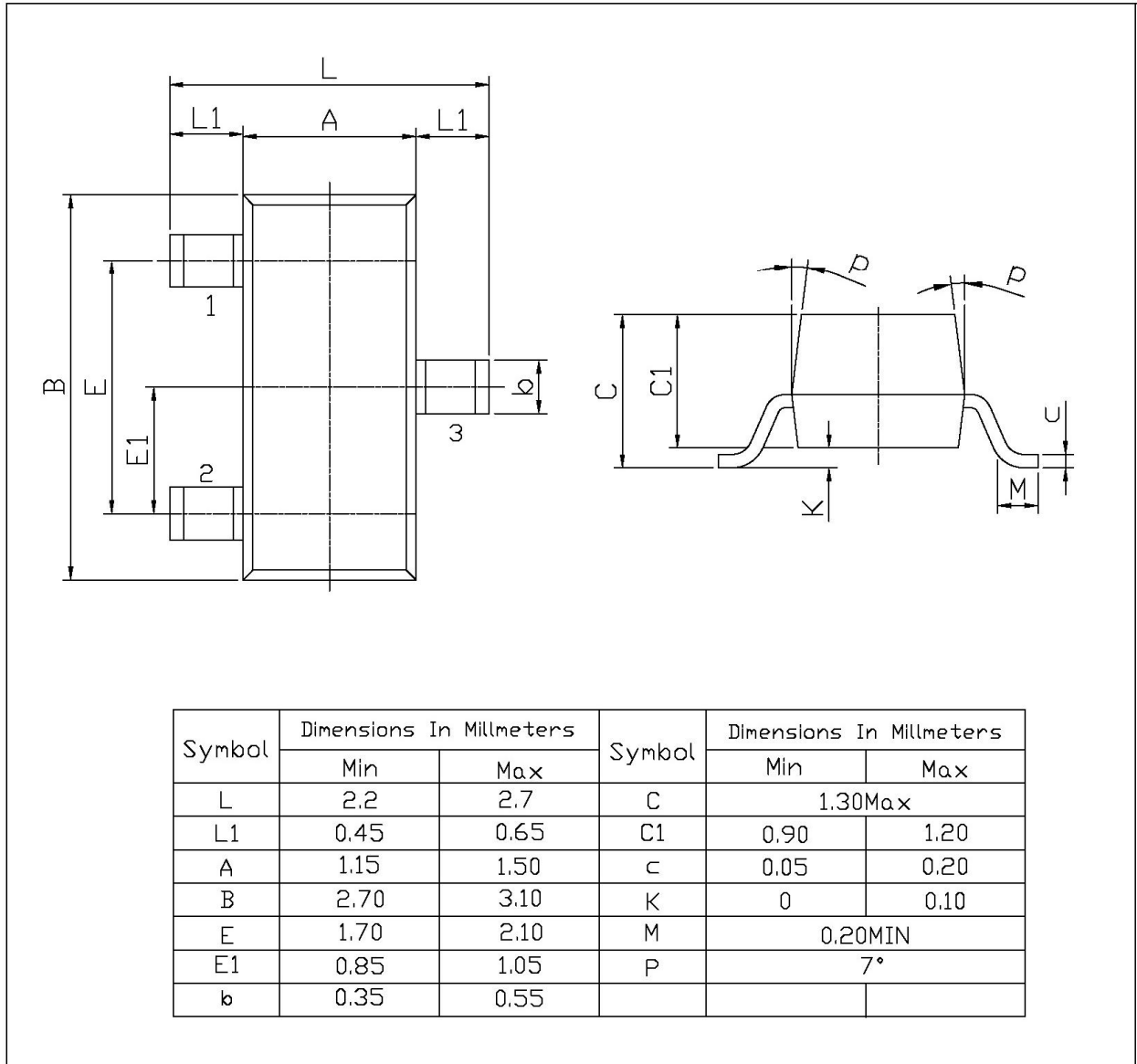
电参数曲线图 / Electrical Characteristic Curve



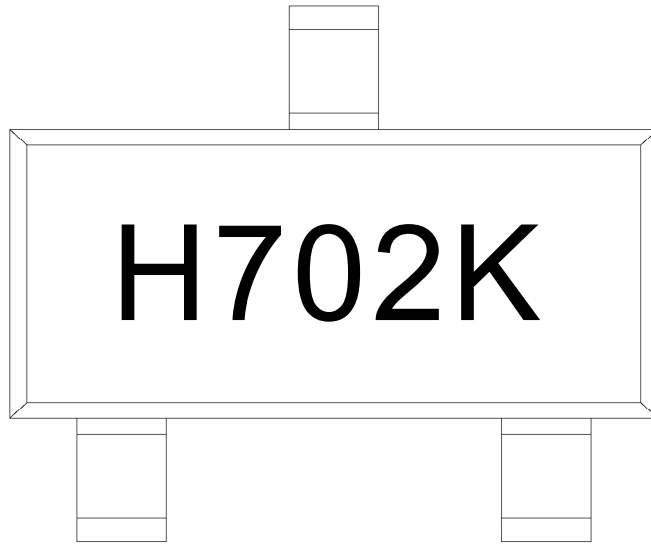
外形尺寸图 / Package Dimensions

SOT-23

单位: mm



印章说明 / Marking Instructions



说明：

H： 为公司代码

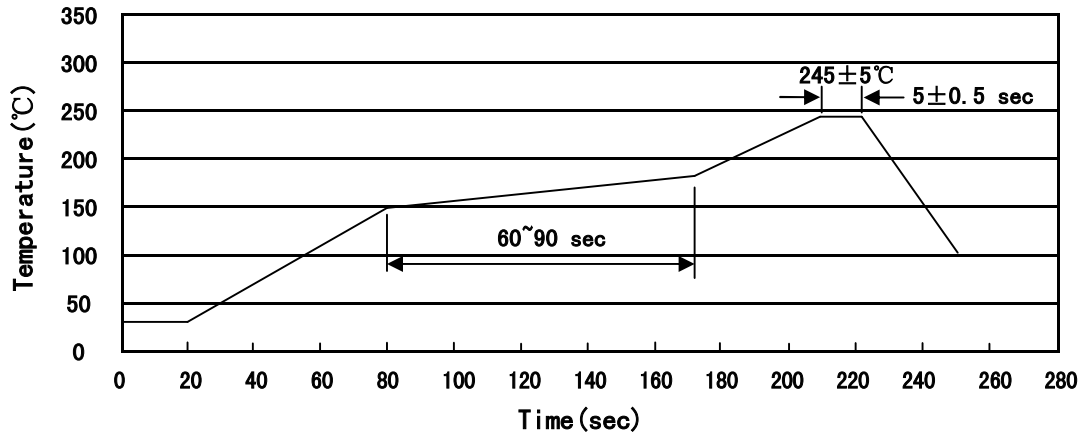
702K： 为型号代码

Note:

H: Company Code

702K: Product Type

**回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)**



说明：

- 1、预热温度 150 ~ 180°C，时间 60 ~ 90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

**耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions**

温度：260±5°C      时间：10±1 sec.      Temp.:260±5°C      Time:10±1 sec

**包装规格 / Packaging SPEC.**

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7" ×8	180×120×180	390×385×205

**使用说明 / Notices**